

Reg No.: \_\_\_\_\_

Name: \_\_\_\_\_

**APJ ABDUL KALAM TECHNOLOGICAL UNIVERSITY**  
**EIGHTH SEMESTER B.TECH DEGREE EXAMINATION, MAY 2019**

**Course Code: EC402**  
**Course Name: NANOELECTRONICS**

Max. Marks: 100

Duration: 3 Hours

**PART A**

*Answer any two full questions, each carries 15 marks.*

Marks

- |   |   |             |
|---|---|-------------|
| 1 | a) Explain the different characteristic lengths in a mesoscopic system?<br>b) Describe parabolic quantum well.  | (10)<br>(5) |
| 2 | a) Starting from Schrodinger equation, show that the density of states in a 1D semiconductor material is directly proportional to $1/\sqrt{E}$<br>b) Differentiate between dry and wet oxidation methods. | (10)<br>(5) |
| 3 | a) Explain sol-gel process for fabrication of nano-particles<br>b) Brief up laser ablation method for nano material deposition with significance on RHEED screen.   | (9)<br>(6)  |

**PART B**

*Answer any two full questions, each carries 15 marks.*

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|---|---|-------------|
| 4 | a) Explain with neat diagram different types of specimen interactions taking place in a sample during SEM.<br>b) Explain Multiple Quantum Wells and its different types with neat diagrams. | (10)<br>(5) |
| 5 | a) Explain Kronig-Penney model for superlattice and zone folding.<br>b) Explain the concept of modulation doping.   | (10)<br>(5) |
| 6 | a) Explain the working of XRD analyzer and how it can be used to analyze a crystal.<br>b) Explain the working principle of Atomic Force Microscope.   | (10)<br>(5) |

**PART C**

*Answer any two full questions, each carries 20 marks.*

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|---|--|--------------------|
| 7 | a) Write notes on the following scattering mechanisms (a) Electron-phonon scattering (b) Impurity scattering (c) Surface roughness scattering (d) Inter sub band scattering<br>b) Explain the principle of carbon nano tube transistors and its three different types.<br>c) List the advantages of heterojunction quantum wells in MODFETs? | (10)<br>(6)<br>(4) |
|---|--|--------------------|

- 8 a) Illustrate the principle of operation of Resonant tunnelling diode. (8)
- b) Explain the Aharonov-Bohm effect to induced phase variations in electron waves with the application of magnetic field with the help of diagrams and equations.. (8)
- c) Explain the concept of hot electrons. (4)
- 9 a) Explain the concept of coulomb blockade. Obtain the conditions to be fulfilled to observe single electron effect. (10)
- b) Explain the device structure and working of DH laser. (5)
- c) Write notes on NEMS. (5)

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